

To all our customers

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Renesas Technology Corp.  
Customer Support Dept.  
April 1, 2003

## Cautions

Keep safety first in your circuit designs!

1. Renesas Technology Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

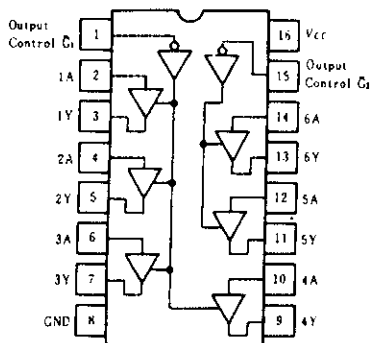
Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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# HD74LS367A ●Hex Bus Drivers (non-inverted data outputs with three-state outputs)

## ■ PIN ARRANGEMENT



(Top View)

## ■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Ratings	Unit
Supply voltage	$V_{CC}$	7.0	V
Input voltage	$V_{IN}$	7.0	V
Output voltage (off-state)	$V_{O,off}$	5.5	V
Operating temperature range	$T_{opr}$	-20 ~ +75	°C
Storage temperature range	$T_{stg}$	-65 ~ +150	°C

## ■ FUNCTION TABLE

$\bar{G}$	A	Y
H	X	Z
L	L	L
L	H	H

Note) H; high level, L; low level,  
X; irrelevant  
Z; off (high-impedance) state  
of a 3-state output

## ■ RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	Unit
Output current	$I_{OH}$	—	—	-2.6	mA
Output current	$I_{OL}$	—	—	24	mA

## ■ ELECTRICAL CHARACTERISTICS ( $T_a = -20 \sim +75^\circ\text{C}$ )

Item	Symbol	Test Conditions	min	typ*	max	Unit	
Input voltage	$V_{IH}$		2.0	—	—	V	
	$V_{IL}$		—	—	0.8	V	
Output voltage	$V_{OH}$	$V_{CC}=4.75\text{V}, V_{IH}=2\text{V}, V_{IL}=0.8\text{V}, I_{OH}=-2.6\text{mA}$	2.4	—	—	V	
	$V_{OL}$	$V_{CC}=4.75\text{V}, V_{IH}=2\text{V}, V_{IL}=0.8\text{V}$	$I_{OL}=24\text{mA}$	—	—	0.5	V
			$I_{OL}=12\text{mA}$	—	—	0.4	
Output current	$I_{OZ}$	$V_{CC}=5.25\text{V}, V_{IH}=2\text{V}, V_{IL}=0.8\text{V}$	$V_o=2.4\text{V}$	—	—	20	$\mu\text{A}$
			$V_o=0.4\text{V}$	—	—	-20	
				—	—	—	
Input current	$I_{IH}$	$V_{CC}=5.25\text{V}, V_I=2.7\text{V}$	—	—	20	$\mu\text{A}$	
	$I_{IL}$	A inputs $V_{CC}=5.25\text{V}$	$V_I=0.5\text{V}, \bar{G}$ inputs 2V	—	—	-20	$\mu\text{A}$
			$V_I=0.4\text{V}, \bar{G}$ inputs 0.4V	—	—	-0.4	mA
		$\bar{G}$ inputs $V_{CC}=5.25\text{V}, V_I=0.4\text{V}$	—	—	-0.4	mA	
$I_I$	$V_{CC}=5.25\text{V}, V_I=7\text{V}$	—	—	0.1	mA		
Short-circuit output current	$I_{OS}$	$V_{CC}=5.25\text{V}$	-40	—	-225	mA	
Supply current**	$I_{CC}$	$V_{CC}=5.25\text{V}$	—	14	24	mA	
Input clamp voltage	$V_{IK}$	$V_{CC}=4.75\text{V}, I_{IH}=-18\text{mA}$	—	—	-1.5	V	

\*  $V_{CC}=5\text{V}, T_a=25^\circ\text{C}$

\*\*  $I_{CC}$  is measured with data inputs grounded and output control inputs at 4.5V.

## ■ SWITCHING CHARACTERISTICS ( $V_{CC}=5\text{V}, T_a=25^\circ\text{C}$ )

Item	Symbol	Test Conditions	min	typ	max	Unit	
Propagation delay time	$t_{PLH}$	$C_L=45\text{pF}, R_L=667\Omega$	—	10	16	ns	
	$t_{PHL}$		—	9	22		
Output enable time	$t_{ZH}$		$C_L=5\text{pF}, R_L=667\Omega$	—	19	35	ns
	$t_{ZL}$			—	24	40	
Output disable time	$t_{HZ}$			—	—	30	ns
	$t_{LZ}$			—	—	35	

Note) Refer to Test Circuit and Waveform of the Common Item



Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	FP-16DN
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EIAJ	Conforms
Weight (reference value)	0.15 g

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